



District 9220

A brief history of microelectronics





First computer: ENIAC (1945)

ENIAC was completed in 1945 and is regarded as the first successful, general digital computer. It weighed more than 27,000 kg (60,000 lb), and contained more than 18,000 vacuum tubes.



http://www.ideafinder.com/history/inventions/comeniac.htm

Vacuum tubes



Beginning of miniaturization ...



First transistor (Bell Labs, USA, 1947)



From November 17, 1947 to December 23, 1947, John Bardeen and Walter Brattain at AT&T's Bell Labs in the United States performed experiments and observed that when two gold point contacts were applied to a crystal of germanium, a signal was produced with the output power greater than the input. Solid State Physics Group leader William Shockley saw the potential in this, and over the next few months worked to greatly expand the knowledge of semiconductors. The term transistor was coined by John R. Pierce as a contraction of the term transresistance

In acknowledgement of this accomplishment, **Shockley, Bardeen, and Brattain** were jointly awarded the 1956 Nobel Prize in Physics "for their researches on semiconductors and their discovery of the transistor effect."



INTEGRATED CIRCUIT - 1958

Jack Kilby, inventor of the integrated circuit
Nobel prize in Physics, 2000

20 BO NO.043601 DATE Junt 12, 1958

- and the former has been prog that The walks

 US Patent # 3,138,743 filed Feb. 6, 1959





Early Integrated Circuit (4 transistors), 1959



Contains only 4 transistors !

(Bipolar transistors)

> Same year: first Barbie doll presented at a show in NYC



Early Integrated Circuit (200 transistors), 1969



(MOS transistors)

Same year:

First man on the Moon



Woodstock festival



NVIDIA's Tesla K20 (7,000,000,000 transistors), 2012



NVIDIA's Pascal GPU (17,000,000,000 transistors), 2016



Samsung 1Tb (128 TB) VNAND Flash (2017)

1Tb+4 = 256×10⁹ transistors



Samsung has now also announced their fifth-generation V-NAND, which will increase the layer count further to 96 layers with relatively few other changes to the design. The fifth generation will include Samsung's first QLC NAND flash (four bits per cell), with a capacity of 1Tb (128GB) per die.

http://www.anandtech.com/show/11703/samsung-at-flash-memory-summit-96layer-vnand-mlc-znand-new-interfaces

2015 Apple watch has twice the processing power as 1985 Supercomputer



Cray II Supercomputer With liquid cooling 1985

Moore's law (1965 – 2017)



Figure 1.1 Evolution of the number of transistors per chip with time. Central processing units (CPU) or microprocessors and graphics processing units (GPU) or graphics processors from different vendors are shown. The top of the chart shows the date of introduction of some landmark products: HP-35 pocket calculator, Apple II and Macintosh computers, iPod, iPhone, and the introduction second, third and fourth-generation mobile phone networks (2G, 3G, 4G).

Moore's law

In 2014, semiconductor production facilities made some 250 billion billion (250 x 10¹⁸) transistors. This was, literally, production on an astronomical scale.

Every second of that year, on average, 8 trillion transistors were produced. That figure is about 25 times the number of stars in the Milky Way and some 75 times the number of galaxies in the known universe.



Scaling: continuous reduction of transistor size



To boost performance: Elements used in Silicon processing

hydrogen	II.				198()'s	2	010	's				Ш	IV	v	VI	VII	O
1								010										He
1.00794(7) lithium 3	beryllium 4				<mark>199</mark> (D's	E	HgCdTe ccimer litl	10				boron 5	carbon 6	nitrogen 7	oxygen 8	fluorine 9	4.002602(2) neon 10
Li	Be		20001-									В	С	N	0	F	Ne	
6.941(2) sodium 11	9.012182(3) magnesium 12				2000's			Radioactive					10.811(7) aluminium 13	12.0107(8) silicon 14	14.00674(7) phosphorus 15	15.9994(3) sulfur 16	18.9984032(5) chlorine 17	20.1797(6) argon 18
Na 22.989770(2)	Mg 24.305(?)												AI 26.981538(2)	Si 28.0855(3)	P 30.973761(2)	S 32.066(6)	CI 35.4527(9)	Ar 39.948(1)
^{potassium} 19	calcium 20		scandium 21	titanium 22	vanadium 23	chromium 24	manganese 25	iron 26	cobalt 27	nickel 28	copper 29	zinc 30	gallium 31	germanium 32	arsenic 33	selenium 34	bromine 35	krypton 36
K 39.0983(1)	Ca 40.078(4)		Sc 44.965910(8)	47.867(1)	50.9415(1)	Cr 51.9961(6)	Mn 54.938049(9)	Fe 55.845(2)	Co 58.933200(9)	Ni 58.6034(2)	Cu 63.546(3)	Zn 65.39(2)	Ga 89.723(1)	Ge 72.61(2)	As 74.92160(2)	Se 78 96(3)	Br 79.904(1)	Kr 83.80(1)
rubidium 37	strontium 38		yttrium 39	zirconium 40	niobium 41	molybdenum 42		ruthenium 44	rhodium 45	palladium 46	silver 47	cadmium 48	indium 49	tin 50	antimony 51	tellurium 52	iodine 53	xenon 54
Rb 85.4678(3)	Sr 87.62(1)		Y 88.90585(2)	Zr 91.224(2)	Nb 52.90638(2)	Mo 95.94(1)	TC [98.9063]	Ru 101.07(2)	Rh 102.90550(2)	Pd 106.42(1)	Ag 107.8682(2)	Cd 112.411(8)	114.818(3)	Sn 118 710(7)	Sb 121.760(1)	Te 127.60(3)	126.90447(3)	Xe 131 29(2)
caesium 55	barium 56		lanthanum 57	^{hafnium} 72	tantalum 73	tungsten 74	rhenium 75	osmium 76	iridium 77	platinum 78	^{gold} 79	mercury 80	thallium 81	lead 82	bismuth 83			
CS 132.90545(2)	Ba 137.327(7)		La 138.9055(2)	178.49(2)	Ta 180.9479(1)	183.84(1)	Re 186.207(1)	Os 190.23(3)	192.217(3)	Pt 195.078(2)	Au 196.96655(2)	Hg 200.59(2)	204.3833(2)	Pb 207.2(1)	Bi 208.99038(2)	Po [208.9824]	At [209.9871]	Rn [222.0176]
				h				h	0	h	()()		h	<u> </u>	h		1	I
Fr [223.0197]	Ra [226.0254]		58	praseodymium 59	nedodymium 60		samarium 62	europium 63	gadolinium 64	terbium 65	dysprosium 66	holmium 67	erbium 68	thulium 69	ytterbium 70	lutetium 71		
			Ce 140.116(1)	Pr 140.90765(2)	Nd 144.24(3)	Pm [144.9127]	Sm 150.36(3)	Eu 151.964(1)	Gd 157 25(3)	Tb 158.92534(2)	Dy 162.50(3)	HO 164.93032(2)	Er 167.26(3)	168.53421(2)	Yb 173.04(3)	LU 174.967(1)		
			Th	Pa	238.0289(1)	Np	Pu	Am	Cm	Bk	Cf	ES	Fm	Md	NO [259.1011]	[262.110]		

Figure 1.7 Elements used in semiconductor (silicon) industry. Radioactive elements cannot be used for obvious reasons.

Printing small things: Photolithography



Price of lithography equipment



Cost of Semiconductor Fabs (> \$10 Billion)



Cost of Semiconductor Fabs (> \$10 Billion)



Semiconductor manufacturing per country



China + Taiwan + Japan + Korea + SE Asia = 77% of world production

Multigate transistors



>A: Single-gate planar bulk MOSFET. ➢B: Single-gate SOI **MOSFET** with mesa isolation. C: Triple-gate (trigate) SOI nanowire MOSFET with square cross section. >D: Bulk trigate **MOSFET** with high aspect ratio (bulk FinFET). E: SOI trigate MOSFET with high aspect ratio (SOI FinFET). F: Pi-gate (∏-gate) SOI nanowire MOSFET. \succ G: Omega-gate (Ω gate) SOI nanowire MOSFET. > H: Horizontal gate-allaround (GAA, quadruple-gate, quadgate) nanowire transistor with square section. >I: Vertical gate-allaround (GAA) nanowire **MOSFET** with circular cross section).

Figure 2.1 Different types of MOSFETs sorted by gate configuration.

Stacked GAA nanowire transistors



IBM/GF/Samsung Claims 5nm Nanosheet Breakthrough (2017 VLSI Symposium) https://www.wired.com/2017/06/ibm-silicon-nanosheets-transistors/

Three-dimensional (3D) monolithic integration



Fig.2: TEM cross-section of the 3D sequential structure up to M2 line. Nanometric top and bottom transistors alignment is observed.

http://www.advancedsubstratenews.com/2016/05/fd-soi-in-short-courses-papers-and-talks-at-upcoming-vlsi-symposia-16/





Where are we going? (good side)







Tablet



Universal translator

/ Laptop

Cell phone













Where are we going? (not so good side)









Mark Zuckerberg (Facebook) puts tape on his laptop camera and a phone jack into his microphone input



https://www.hackread.com/wp-content/uploads/2016/06/Mark-Zuckerberg-Tape-Facebook-Instagram-1-796x398.jpg

By some estimates, as many as a million CCTV cameras are installed in London, making it the most surveilled metropolis on the planet. Boris Johnson, who before becoming Britain's Foreign Secretary served as the city's mayor, once said, "When you walk down the streets of London, you are a movie star. You are being filmed by more cameras than you can possibly imagine." http://www.newyorker.com/magazine/2016/08/22/londons-super-recognizer-police-force



"If we build these devices to take care of everything for us, eventually they'll think faster than us and THEY'LL GET **RID OF THE SLOW HUMANS** to run companies more efficiently." -Steve Wozniak

HUFF POST

Stephen Hawking, Elon Musk, and Bill Gates Warn About Artificial Intelligence



Some of the most popular sci-fi movies—2001: A Space Odyssey, The Terminator, The Matrix, Transcendence, Ex Machina, and many others—have been based on the notion that artificial intelligence will evolve to a point at which humanity will not be able to control its own creations, leading to the demise of our entire civilization. This fear of rapid technology growth and our increasing dependence on it is certainly warranted, given the capabilities of current machines built for military purposes.

Already, technology has had a significant impact on warfare since the Iraq war began in 2001. Unmanned drones provide sustained surveillance and swift attacks on targets, and small robots are used to disarm improvised explosive devices. The military is currently <u>funding</u> research to produce more <u>autonomous and self-aware robots</u> to diminish the need for human soldiers to risk their lives. Founder of Boston Dynamics, Marc Raiber, released a video showing a terrifying six-foot tall, 320-lb. humanoid robot named Atlas, running freely in the woods. The company, which was <u>bought by Google</u> in 2013 and receives grant money from the Department of Defense, is working on developing an even more agile version.